# General purpose (dual digital transistors) UMD3N / IMD3A

### Features

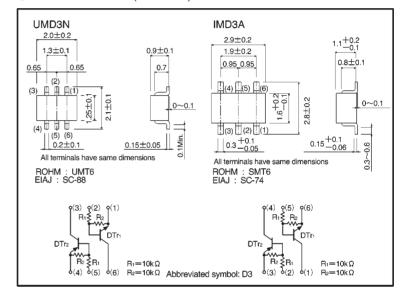
- Both the DTA114E chip and DTC114E chip in a UMT or SMT package.
- Mounting possible with UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

# Structure

Epitaxial planar type NPN/PNP silicon transistor (Built-in resistor type)

The following characteristics apply to both DTr<sub>1</sub> and DTr<sub>2</sub>, however, the "–" sign on DTr<sub>2</sub> values for the PNP type have been omitted.

# External dimensions (Units: mm)



## ■Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit	
Supply voltage		Vcc	50	V	
Input voltage		M	-10	V	
		Vin	40		
Output current		lo	50	m A	
		Ic(Max.)	100	mA	
Power dissipation	UMD3N	Pd	150(TOTAL)	mW *1	
	IMD3A	Pu Pu	300 (TOTAL)	*2	
Junction temperature		Tj 150		င	
Storage temperature		Tstg	−55~+150	°C	

ROHM

\*1 120mW per element must not be exceeded.

\*2 200mW per element must not be exceeded.

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# ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	VI (off)	_	_	0.5	٧	Vcc=5V, Io=100 μ A
Input voltage	VI (on)	3	_	_		Vo=0.3V, Io=10mA
Output voltage	Vo(on)	_	0.1	0.3	V	lo=10mA, l:=0.5mA
Input current	lı	_	_	0.88	mA	V <sub>1</sub> =5V
Output current	IO(off)	_	_	0.5	μΑ	Vcc=50V, Vi=0V
DC current gain	Gı	30	_	_	_	Vo=5V , Io=5mA
Transition frequency	f⊤	_	250	_	MHz	Vc=10mA, I=-5mA, f=100MHz *
Input resistance	R <sub>1</sub>	7	10	13	kΩ	_
Resistance ratio	R2/R1	0.8	1	1.2	_	_

<sup>\*</sup> Transition frequency of the device

# Packaging specifications

	Packaging type	Tap	oing
	Code	TR	T108
Part No.	Basic ordering unit (pieces)	3000	3000
UMD3N		0	_
IMD3A		_	0

# ●Electrical characteristic curves DTr₁ (NPN)

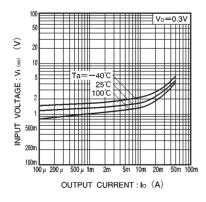


Fig.1 Input voltage vs. output current (ON characteristics)

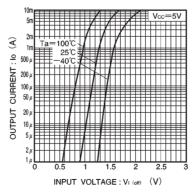


Fig.2 Output current vs. input voltage (OFF characteristics)

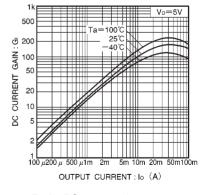


Fig.3 DC current gain vs. output current

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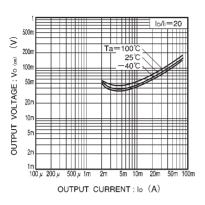


Fig.4 Output voltage vs. output current

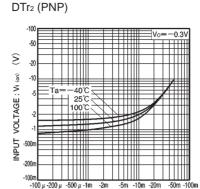


Fig.5 Input voltage vs. output current (ON characteristics)

OUTPUT CURRENT: lo (A)

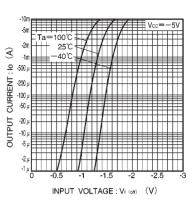


Fig.6 Output current vs. input voltage (OFF characteristics)

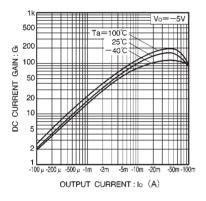


Fig.7 DC current gain vs. output current

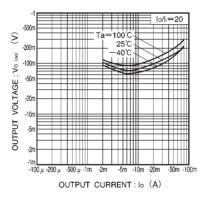


Fig.8 Output voltage vs. output current